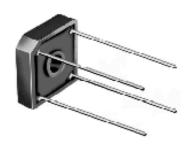
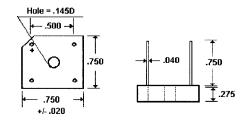
# 8.0 Amp SINGLE PHASE SILICON BRIDGE

#### **Description**

### **Mechanical Dimensions**





**Mechanical Data:** Mounting Position - Any. Weight - 20 Grams.

#### **Features**

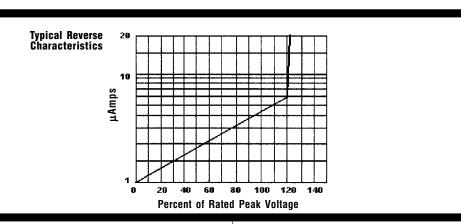
- COMPACT SIZE
- **LOW LEAKAGE CURRENT**

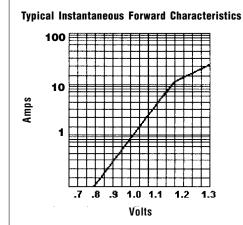
- 125 AMP SURGE OVERLOAD RATING
- MEETS UL SPECIFICATION 94V-0

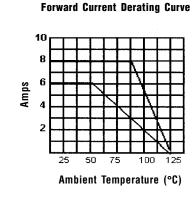
Electrical Characteristics @ 25°C.	KBPC800 810 Series							Units
Maximum Ratings	KBPC800	KBPC801	KBPC802	KBPC804	KBPC806	KBPC808	KBPC810	
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
RMS Reverse VoltageV <sub>R(rms)</sub>	35	70	140	280	420	560	700	Volts
DC Blocking VoltageV <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Average Forward Rectified CurrentI $_{F(av)}$ $T_{c} = 100^{\circ}C$ $T_{A} = 50^{\circ}C$								Amp:
Non-Repetitive Peak Forward Surge CurrentI <sub>FSM</sub> 8.3 mS Single ½ Sine Wave Imposed on Rated Load				150				Amp
Rating for Fusing (T < 8.3 mS)				127				A <sup>2</sup> S
Forward VoltageV <sub>F</sub> Bridge Element @ 8.0 Amps				1.2				Volts
DC Reverse CurrentI <sub>R</sub> @ Rated DC Blocking Voltage $T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$								μAmp mAmp
Typical Junction Capacitance $C_J$	<	1	86	>	<	90	>	pF
Operating & Storage Temperature RangeT <sub>J</sub> , T <sub>STRG</sub>				55 to 150				°C

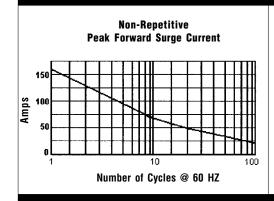


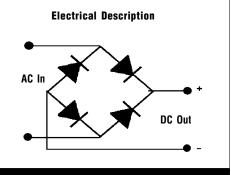
## 8.0 Amp SINGLE PHASE SILICON BRIDGE











Ratings at 25 Deg. C ambient temperature unless otherwise specified.

Single Phase Half Wave, 60 HZ Resistive or Inductive Load.

For Capacitive Load, Derate Current by 20%.